

Data sheet acquired from Harris Semiconductor SCHS021D – Revised September 2003

## **CMOS NAND GATES**

High-Voltage Types (20-Volt Rating)

Quad 2 Input - CD4011B Dual 4 Input - CD4012B Triple 3 Input - CD4023B

■ CD4011B, CD4012B, and CD4023B NAND gates provide the system designer with direct implementation of the NAND function and supplement the existing family of CMOS gates. All inputs and outputs are buffered.

The CD4011B, CD4012B, and CD4023B types are supplied in 14-lead hermetic dual-in-line ceramic packages (F3A suffix), 14-lead dual-in-line plastic packages (E suffix), 14-lead small-outline packages (M, MT, M96, and NSR suffixes), and 14-lead thin shrink small-outline packages (PWR suffix). The CD4011B and CD4023B types also are supplied in 14-lead thin shrink small-outline packages (PW suffix).

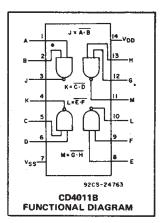
#### Features:

- Propagation delay time = 60 ns (typ.) at C<sub>L</sub> = 50 pF, V<sub>DD</sub> = 10 V
- Buffered inputs and outputs
- Standardized symmetrical output characteristics
- Maximum input current of 1 μA at 18 V over full package temperature range; 100 nA at 18 V and 25°C
- 100% tested for quiescent current at 20 V
- 5-V, 10-V, and 15-V parametric ratings
- Noise margin (over full package temperature range:

1 V at V<sub>DD</sub> = 5 V 2 V at V<sub>DD</sub> = 10 V

2.5 V at V<sub>DD</sub> = 15 V ■ Meets all requirements of JEDEC Tentative

 Meets all requirements of JEDEC Tentative Standard No. 13B, "Standard Specifications for Description of "B" Series CMOS Devices"



### MAXIMUM RATINGS, Absolute-Maximum Values:

DC SUPPLY-VOLTAGE RANGE, ( $V_{DD}$ )

Voltages referenced to  $V_{SS}$  Terminal)

-0.5V to +20V

INPUT VOLTAGE RANGE, ALL INPUTS

-0.5V to  $V_{DD}$  +0.5V

DC INPUT CURRENT, ANY ONE INPUT

±10mA

POWER DISSIPATION PER PACKAGE ( $P_{D}$ ):

For  $T_{A}$  = -55°C to +100°C

500mW

For  $T_{A}$  = +100°C to +125°C.

Derate Linearity at 12mW/°C to 200mW

DEVICE DISSIPATION PER OUTPUT TRANSISTOR

FOR  $T_{A}$  = FULL PACKAGE-TEMPERATURE RANGE (All Package Types)

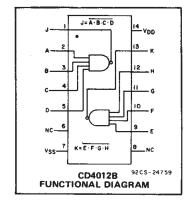
100mW

OPERATING-TEMPERATURE RANGE ( $T_{A}$ )

-55°C to +125°C

STORAGE TEMPERATURE RANGE ( $T_{A}$ )

-65°C to +150°C

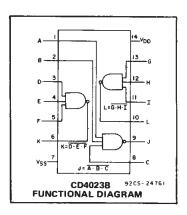


#### RECOMMENDED OPERATING CONDITIONS

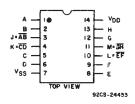
LEAD TEMPERATURE (DURING SOLDERING):

For maximum reliability, nominal operating conditions should be selected so that operation is always within the following ranges:

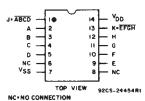
CHARACTERISTIC	LIM	IITS	LINUTO
CHARACTERISTIC	MIN.	MAX.	UNITS
Supply-Voltage Range (For T <sub>A</sub> = Full Package Temperature Range)	3	18	v

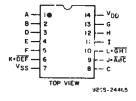


#### **TERMINAL ASSIGNMENTS**



CD4011B





CD4012B

CD4023B

#### STATIC ELECTRICAL CHARACTERISTICS

CHARACTER-	COND	HOITION	IS	LIMI:	rs at i	NDICAT	ED TEI	MPERA	TURES (	OC)	UNITS	
ISTIC	Vo	VIN	VDD					+25			ONTI	
	(V)	(V)	(V)	-55	-40	+85	+125	Min.	Тур.	Max.		
Quiescent Device Current, IDD Max.	_	0,5	5	0.25	0.25	7.5	7.5	-	0.01	0.25		
		0,10	10	0.5	0.5	15	. 15	-	0.01	0.5	μΑ	
		0,15	15	1	1	30	30	-	0.01	1	μΑ	
	_	0,20	20	5	5	150	150	-	0.02	5		
Output Low (Sink) Current IOL Min.	0.4	0,5	5	0.64	0.61	0.42	0.36	0.51	1			
	0.5	0,10	10	1.6	1.5	1.1	0.9	1.3	2.6	_		
	1.5	0,15	15	4.2	4	2.8	2.4	3.4	6.8	_		
Output High (Source) Current, IOH Min.	4.6	0,5	5	-0.64	-0.61	-0.42	-0.36	-0.51	-1	-	mA	
	2.5	0,5	5	-2	-1.8	-1.3	-1.15	-1.6	-3.2	-		
	9.5	0,10	10	-1.6	-1.5	-1.1	-0.9	-1.3	-2.6	-		
	13.5	0,15	15	-4.2	-4	-2.8	-2.4	-3.4	-6.8	_		
Output Voltage:	_	0,5	5		0	.05		_	0	0.05		
Low-Level, VOL Max.	_	0,10	10		0	.05		_	0	0.05		
VOL MAX.	-	0,15	15		0	.05		_	0	0.05	v	
Output Voltage:	<b>–</b> .	0,5	5		4	.95		4.95	5	-		
High-Level,	-	0,10	10		9	.95		9.95	10	_		
VOH Min.	-	0,15	15		14	4.95		14.95	15	-		
Input Low	4.5	-	5			1.5		<u> </u>	_	1.5		
Voltage,	9	-	10			3		-		3	]	
VIL Max.	13.5	_	15			4	<u> </u>	_	I –	4	] ,	
Input High Voltage, V <sub>IH</sub> Min.	0.5,4.5	-	5			3.5		3.5	_	_	\   	
	1,9	_	10			7		7				
	1.5,13.5	-	15			11		11	_	_		
Input Current I <sub>IN</sub> Max.		0,18	18	±0.1	±0.1	±1	±1	-	±10 <sup>-5</sup>	±0.1	μА	

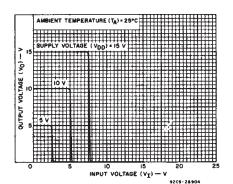


Fig. 1 — Typical voltage transfer characteristics.

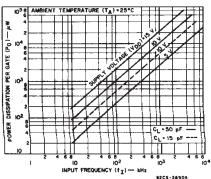


Fig.2 - Typical power dissipation characteristics.

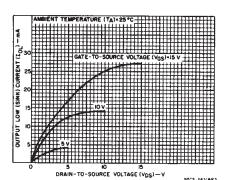


Fig.3 — Typical output low (sink) current characteristics.

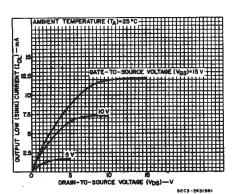


Fig.4 — Minimum output low (sink) current characteristics.

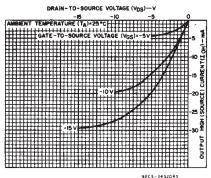


Fig.5 - Typical output high (source) current characteristics.

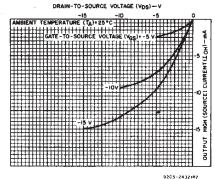
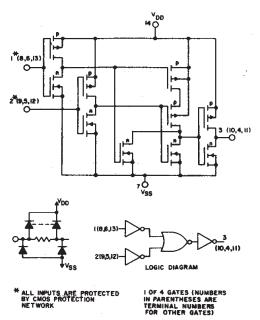


Fig.6 - Minimum output high (source) current characteristics.



2(12)
3(11)
4(10)
5(9)
COGIC DIAGRAM

LOGIC DIAGRAM

LOGIC DIAGRAM

LOGIC DIAGRAM

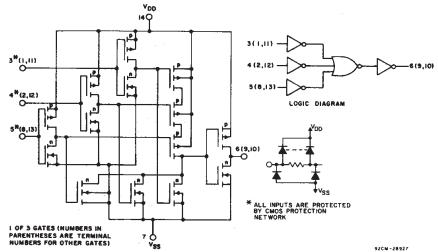
TOPACHETESES ARE TERMINAL PARENTHESES ARE TERMINAL PARENTHESES ARE TERMINAL NUMBERS TOP OTHER GATES)

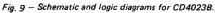
NUMBERS TOP OTHER GATES)

SECH-28928

Fig.7 - Schematic and logic diagrams for CD4011B.

Fig.8 — Schematic and logic diagrams for CD4012B.





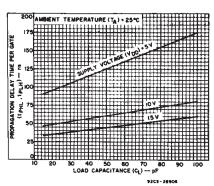


Fig. 10 - Typical propagation delay time per gate as a function of load capacitance.

#### **DYNAMIC ELECTRICAL CHARACTERISTICS**

At  $T_A = 25^{\circ}C$ ; Input  $t_r$ ,  $t_f = 20$  ns,  $C_L = 50$  pF,  $R_L = 200 \mathrm{k}\Omega$ 

CHARACTERISTIC	TEST CONDI	TIONS	LIN	UNITS	
		V <sub>DD</sub> VOLTS	TYP.	MAX.	UNITS
Propagation Delay Time, <sup>‡</sup> PHL, <sup>†</sup> PLH		5	125	250	
		10	60	120	ns
		15	45	90	
		5	100	200	
Transition Time,		10	50	100	ns
ካዘር ካርዘ		15	40	80	
Input Capacitance, CIN	Any Input		5	7.5	pF

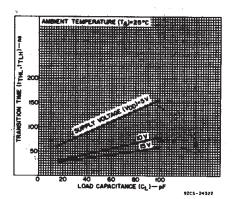


Fig. 11 — Typical transition time as a function of load capacitance,

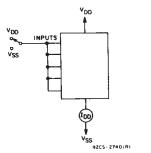


Fig. 12 - Quiescent-device-current test circuit.

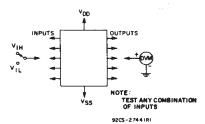


Fig. 13 - Input-voltage test circuit.

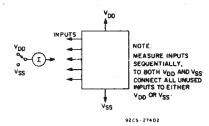
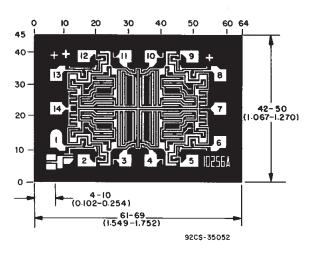
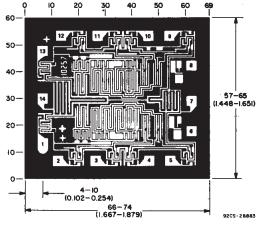


Fig. 14 - Input-current test circuit.

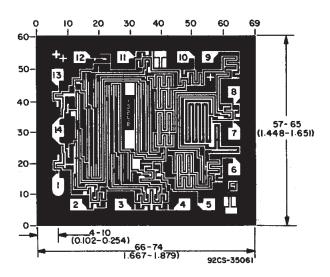
#### Chip Dimensions and Pad Layouts



CD4011BH



CD4012BH



CD4023BH

Dimensions in parentheses are in millimeters and are derived from the basic inch dimensions as indicated. Grid graduations are in mils ( $10^{-3}$  inch).





www.ti.com 24-Nov-2024

## **PACKAGING INFORMATION**

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
CD4011BE	ACTIVE	PDIP	N	14	25	RoHS & Green	NIPDAU	N / A for Pkg Type	-55 to 125	CD4011BE	Samples
CD4011BEE4	ACTIVE	PDIP	N	14	25	RoHS & Green	NIPDAU	N / A for Pkg Type	-55 to 125	CD4011BE	Samples
CD4011BF	ACTIVE	CDIP	J	14	25	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	CD4011BF	Samples
CD4011BF3A	ACTIVE	CDIP	J	14	25	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	CD4011BF3A	Samples
CD4011BM	ACTIVE	SOIC	D	14	50	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CD4011BM	Samples
CD4011BM96	ACTIVE	SOIC	D	14	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CD4011BM	Samples
CD4011BM96E4	ACTIVE	SOIC	D	14	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CD4011BM	Samples
CD4011BME4	ACTIVE	SOIC	D	14	50	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CD4011BM	Samples
CD4011BMT	OBSOLETE	SOIC	D	14		TBD	Call TI	Call TI	-55 to 125	CD4011BM	
CD4011BNSR	ACTIVE	SO	NS	14	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CD4011B	Samples
CD4011BPW	OBSOLETE	TSSOP	PW	14		TBD	Call TI	Call TI	-55 to 125	CM011B	
CD4011BPWR	ACTIVE	TSSOP	PW	14	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CM011B	Samples
CD4011BPWRG4	ACTIVE	TSSOP	PW	14	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CM011B	Samples
CD4012BE	ACTIVE	PDIP	N	14	25	RoHS & Green	NIPDAU	N / A for Pkg Type	-55 to 125	CD4012BE	Samples
CD4012BEE4	ACTIVE	PDIP	N	14	25	RoHS & Green	NIPDAU	N / A for Pkg Type	-55 to 125	CD4012BE	Samples
CD4012BF3A	ACTIVE	CDIP	J	14	25	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	CD4012BF3A	Samples
CD4012BM	OBSOLETE	SOIC	D	14		TBD	Call TI	Call TI	-55 to 125	CD4012BM	
CD4012BM96	ACTIVE	SOIC	D	14	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CD4012BM	Samples
CD4012BM96E4	ACTIVE	SOIC	D	14	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CD4012BM	Samples
CD4012BM96G4	ACTIVE	SOIC	D	14	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CD4012BM	Samples





24-Nov-2024 www.ti.com

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
CD4012BNSR	ACTIVE	SO	NS	14	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CD4012B	Samples
CD4012BPWR	ACTIVE	TSSOP	PW	14	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CM012B	Samples
CD4023BE	ACTIVE	PDIP	N	14	25	RoHS & Green	NIPDAU	N / A for Pkg Type	-55 to 125	CD4023BE	Samples
CD4023BEE4	ACTIVE	PDIP	N	14	25	RoHS & Green	NIPDAU	N / A for Pkg Type	-55 to 125	CD4023BE	Samples
CD4023BF	ACTIVE	CDIP	J	14	25	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	CD4023BF	Samples
CD4023BF3A	ACTIVE	CDIP	J	14	25	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	CD4023BF3A	Samples
CD4023BM	OBSOLETE	SOIC	D	14		TBD	Call TI	Call TI	-55 to 125	CD4023BM	
CD4023BM96	ACTIVE	SOIC	D	14	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CD4023BM	Samples
CD4023BMT	OBSOLETE	SOIC	D	14		TBD	Call TI	Call TI	-55 to 125	CD4023BM	
CD4023BNSR	ACTIVE	SO	NS	14	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CD4023B	Samples
CD4023BPW	OBSOLETE	TSSOP	PW	14		TBD	Call TI	Call TI	-55 to 125	CM023B	
CD4023BPWR	ACTIVE	TSSOP	PW	14	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CM023B	Samples
JM38510/05051BCA	ACTIVE	CDIP	J	14	25	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	JM38510/ 05051BCA	Samples
JM38510/05052BCA	ACTIVE	CDIP	J	14	25	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	JM38510/ 05052BCA	Samples
JM38510/05053BCA	ACTIVE	CDIP	J	14	25	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	JM38510/ 05053BCA	Samples
M38510/05051BCA	ACTIVE	CDIP	J	14	25	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	JM38510/ 05051BCA	Samples
M38510/05052BCA	ACTIVE	CDIP	J	14	25	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	JM38510/ 05052BCA	Samples
M38510/05053BCA	ACTIVE	CDIP	J	14	25	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	JM38510/ 05053BCA	Samples

<sup>(1)</sup> The marketing status values are defined as follows: **ACTIVE:** Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

## PACKAGE OPTION ADDENDUM

www.ti.com 24-Nov-2024

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

**Green:** TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead finish/Ball material Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

**Important Information and Disclaimer:** The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

#### OTHER QUALIFIED VERSIONS OF CD4011B, CD4011B-MIL, CD4012B, CD4012B-MIL, CD4023B, CD4023B-MIL:

Catalog: CD4011B, CD4012B, CD4023B

Military: CD4011B-MIL, CD4012B-MIL, CD4023B-MIL

NOTE: Qualified Version Definitions:

- Catalog TI's standard catalog product
- Military QML certified for Military and Defense Applications



www.ti.com 16-Apr-2024

### TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

#### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



#### \*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CD4011BM96	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
CD4011BNSR	so	NS	14	2000	330.0	16.4	8.45	10.55	2.5	12.0	16.2	Q1
CD4011BPWR	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
CD4012BM96	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
CD4012BNSR	so	NS	14	2000	330.0	16.4	8.2	10.5	2.5	12.0	16.0	Q1
CD4012BPWR	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
CD4023BM96	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
CD4023BNSR	so	NS	14	2000	330.0	16.4	8.45	10.55	2.5	12.0	16.2	Q1
CD4023BPWR	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1



www.ti.com 16-Apr-2024



\*All dimensions are nominal

7th difficitions are norminal							
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
CD4011BM96	SOIC	D	14	2500	356.0	356.0	35.0
CD4011BNSR	so	NS	14	2000	356.0	356.0	35.0
CD4011BPWR	TSSOP	PW	14	2000	356.0	356.0	35.0
CD4012BM96	SOIC	D	14	2500	356.0	356.0	35.0
CD4012BNSR	so	NS	14	2000	356.0	356.0	35.0
CD4012BPWR	TSSOP	PW	14	2000	356.0	356.0	35.0
CD4023BM96	SOIC	D	14	2500	356.0	356.0	35.0
CD4023BNSR	SO	NS	14	2000	356.0	356.0	35.0
CD4023BPWR	TSSOP	PW	14	2000	356.0	356.0	35.0



www.ti.com 16-Apr-2024

### **TUBE**



\*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
CD4011BE	N	PDIP	14	25	506	13.97	11230	4.32
CD4011BE	N	PDIP	14	25	506	13.97	11230	4.32
CD4011BEE4	N	PDIP	14	25	506	13.97	11230	4.32
CD4011BEE4	N	PDIP	14	25	506	13.97	11230	4.32
CD4011BM	D	SOIC	14	50	506.6	8	3940	4.32
CD4011BME4	D	SOIC	14	50	506.6	8	3940	4.32
CD4012BE	N	PDIP	14	25	506	13.97	11230	4.32
CD4012BE	N	PDIP	14	25	506	13.97	11230	4.32
CD4012BEE4	N	PDIP	14	25	506	13.97	11230	4.32
CD4012BEE4	N	PDIP	14	25	506	13.97	11230	4.32
CD4023BE	N	PDIP	14	25	506	13.97	11230	4.32
CD4023BE	N	PDIP	14	25	506	13.97	11230	4.32
CD4023BEE4	N	PDIP	14	25	506	13.97	11230	4.32
CD4023BEE4	N	PDIP	14	25	506	13.97	11230	4.32



SMALL OUTLINE INTEGRATED CIRCUIT



- 1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

  2. This drawing is subject to change without notice.

  3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm, per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.43 mm, per side.
- 5. Reference JEDEC registration MS-012, variation AB.



SMALL OUTLINE INTEGRATED CIRCUIT



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE INTEGRATED CIRCUIT



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



## **MECHANICAL DATA**

## NS (R-PDSO-G\*\*)

# 14-PINS SHOWN

### PLASTIC SMALL-OUTLINE PACKAGE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.



CERAMIC DUAL IN LINE PACKAGE



Images above are just a representation of the package family, actual package may vary. Refer to the product data sheet for package details.

4040083-5/G





CERAMIC DUAL IN LINE PACKAGE



- 1. All controlling linear dimensions are in inches. Dimensions in brackets are in millimeters. Any dimension in brackets or parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
- 2. This drawing is subject to change without notice.
- 3. This package is hermitically sealed with a ceramic lid using glass frit.
- His package is remitted by sealed with a ceramic its using glass mit.
   Index point is provided on cap for terminal identification only and on press ceramic glass frit seal only.
   Falls within MIL-STD-1835 and GDIP1-T14.



CERAMIC DUAL IN LINE PACKAGE



# N (R-PDIP-T\*\*)

## PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- The 20 pin end lead shoulder width is a vendor option, either half or full width.





SMALL OUTLINE PACKAGE



- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

  2. This drawing is subject to change without notice.

  3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-153.



SMALL OUTLINE PACKAGE



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE PACKAGE



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



### **IMPORTANT NOTICE AND DISCLAIMER**

TI PROVIDES TECHNICAL AND RELIABILITY DATA (INCLUDING DATA SHEETS), DESIGN RESOURCES (INCLUDING REFERENCE DESIGNS), APPLICATION OR OTHER DESIGN ADVICE, WEB TOOLS, SAFETY INFORMATION, AND OTHER RESOURCES "AS IS" AND WITH ALL FAULTS, AND DISCLAIMS ALL WARRANTIES, EXPRESS AND IMPLIED, INCLUDING WITHOUT LIMITATION ANY IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE OR NON-INFRINGEMENT OF THIRD PARTY INTELLECTUAL PROPERTY RIGHTS.

These resources are intended for skilled developers designing with TI products. You are solely responsible for (1) selecting the appropriate TI products for your application, (2) designing, validating and testing your application, and (3) ensuring your application meets applicable standards, and any other safety, security, regulatory or other requirements.

These resources are subject to change without notice. TI grants you permission to use these resources only for development of an application that uses the TI products described in the resource. Other reproduction and display of these resources is prohibited. No license is granted to any other TI intellectual property right or to any third party intellectual property right. TI disclaims responsibility for, and you will fully indemnify TI and its representatives against, any claims, damages, costs, losses, and liabilities arising out of your use of these resources.

TI's products are provided subject to TI's Terms of Sale or other applicable terms available either on ti.com or provided in conjunction with such TI products. TI's provision of these resources does not expand or otherwise alter TI's applicable warranties or warranty disclaimers for TI products.

TI objects to and rejects any additional or different terms you may have proposed.

Mailing Address: Texas Instruments, Post Office Box 655303, Dallas, Texas 75265 Copyright © 2024, Texas Instruments Incorporated